

**S.E. (Electrical) (First Sem.) EXAMINATION, 2010**

**ANALOG AND DIGITAL ELECTRONICS**

**(2008 COURSE)**

**Time : Three Hours**

**Maximum Marks : 100**

- N.B. :—**
- (i) Answer any *three* questions from each Section.
  - (ii) Answers to the two Sections should be written in separate answer-books.
  - (iii) Neat diagrams must be drawn wherever necessary.
  - (iv) Figures to the right indicate full marks.
  - (v) Use of logarithmic tables, slide rule, Mollier charts, electronic pocket calculator and steam tables is allowed.
  - (vi) Assume suitable data, if necessary.

**SECTION I**

1. (a) Explain input-output characteristics of CE configuration with neat connection diagram and characteristic curve. [10]
- (b) Explain AC-DC load line analysis using common emitter configuration. [8]

*Or*

2. (a) Draw and explain multistage amplifier. Also state advantages and applications. [6]

- (b) Define the following terms associated with FET :
- (i) Transconduction
  - (ii) Amplification factor. [4]
- (c) What is significance of transfer and drain characteristics of FET ? Draw and explain. [8]
- 3.** (a) Explain with neat diagram Schmitt trigger as an application of op-amp. [8]
- (b) Explain grounded type load voltage to current converter. [8]

*Or*

- 4.** (a) What is the role of op-amp as an instrumentation amplifier? Explain 3-op-amp instrumentation amplifier. [8]
- (b) Explain open loop and close loop configuration of op-amp. [8]
- 5.** (a) Draw and explain monostable multivibrator. Also state applications. [8]
- (b) Using LM317 explain variable voltage regulator with neat diagram. [8]

*Or*

- 6.** (a) Explain sine wave generator using op-amp. Draw output w/fs. [8]
- (b) Explain with neat connection diagram low pass filter. [8]

## SECTION II

7. (a) Convert the following numbers into equivalent BCD : [6]
- (i)  $(11011011)_2$
  - (ii)  $(333)_8$
  - (iii)  $(DB)_{16}$
- (b) State De Morgan's theorem and using Boolean algebra prove the following : [6]
- $$(\bar{A} + B)(A + B + D)\bar{D} = B\bar{D}.$$
- (c) Explain Excess-3 code in detail. [6]

Or

8. (a) If
- $$f = \sum m(4,5,6,7,8,12) + \sum d(1,2,3,9,13,14)$$
- using K-map reduce expression and realise using logic gates. [6]
- (b) Explain binary number system in detail. Also give the difference between binary number system and BCD. [6]
- (c) Design 1-bit comparator using K-map and realise it using logic gates. [6]
9. (a) Explain J-K flip-flop in detail with input and output waveforms. Also give the functions of preset and clear pin. [8]
- (b) Design and explain MOD 5 asynchronous counter with related timing diagram. [8]

*Or*

- 10.** (a) Design 3-bit synchronous up counter using J-K flip-flops and K-map. [8]
- (b) Explain edge triggered and level triggered flip-flops. Also explain D-flip-flop in detail. [8]
- 11.** (a) Explain 1 : 4 demultiplexer along with logic diagram and truth table. [8]
- (b) Explain dual slope ADC in detail. [8]

*Or*

- 12.** Write short notes on : [16]
- (i) Static RAM
- (ii) Dynamic RAM
- (iii) EPROM
- (iv) EEPROM.